

DRAM

MT4LC4M16F5

For the latest data sheet, please refer to the Micron Web site: www.micron.com/mti/msp/html/datasheet.html

FEATURES

- Single +3.3V ±0.3V power supply
- Industry-standard x16 pinout, timing, functions, and packages
- 12 row, 10 column addresses
- High-performance CMOS silicon-gate process
- All inputs, outputs and clocks are LVTTTL-compatible
- FAST PAGE MODE (FPM) access
- 4,096-cycle CAS#-BEFORE-RAS# (CBR) REFRESH distributed across 64ms

OPTIONS

- Plastic Package
50-pin TSOP (400 mil)
- Timing
50ns access
60ns access
- Refresh Rate
Standard Refresh

MARKING

TG
-5
-6
None

Part Number Example

MT4LC4M16F5TG-5

KEY TIMING PARAMETERS

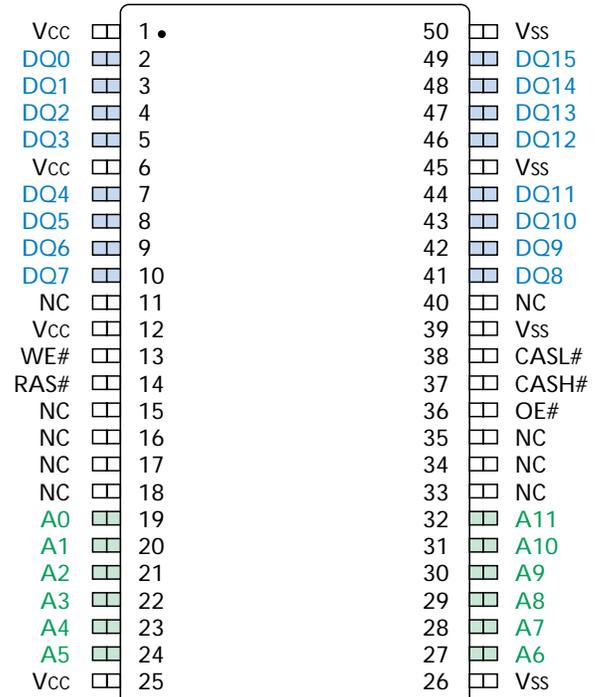
| SPEED | t _{RC} | t _{RAC} | t _{PC} | t _{AA} | t _{CAC} |
|-------|-----------------|------------------|-----------------|-----------------|------------------|
| -5 | 90ns | 50ns | 30ns | 25ns | 13ns |
| -6 | 110ns | 60ns | 35ns | 30ns | 15ns |

GENERAL DESCRIPTION

The 4 Meg x 16 DRAM is a high-speed CMOS, dynamic random-access memory device containing 67,108,864 bits organized in a x16 configuration. The MT4LC4M16F5 is functionally organized as 4,194,304 locations containing 16 bits each. The 4,194,304 memory locations are arranged in 4,096 rows by 1,024 columns. During READ or WRITE cycles, each location is uniquely addressed via the address bits: 12 row-address bits (A0-A11) and 10 column-address bits (A0-A9). In addition, both byte and word accesses are supported via the two CAS# pins (CASL# and CASH#). The CAS# functionality and timing related to address and control functions (e.g., latching column addresses or selecting CBR REFRESH) are such that the internal

PIN ASSIGNMENT (Top View)

50-Pin TSOP



NOTE: 1. The # symbol indicates signal is active LOW.

CAS# signal is determined by the first external CAS# signal (CASL# or CASH#) to transition LOW and the last to transition back HIGH. The CAS# functionality and timing related to driving or latching data are such that each CAS# signal independently controls the associated eight DQ pins.

The row address is latched by the RAS# signal, then the column address by CAS#. The device provides FAST-PAGE-MODE operation, allowing for fast successive data operations (READ, WRITE, or READ-MODIFY-WRITE) within a given row.

The MT4LC4M16F5 must be refreshed periodically in order to retain stored data.

FAST PAGE MODE ACCESS

Each location in the DRAM is uniquely addressable, as mentioned in the General Description. Use of both CAS# signals results in a word access via the 16 I/O pins (DQ0-DQ15). Use of only one of the two results in a BYTE access cycle. CASL# transitioning LOW selects an access cycle for the lower byte (DQ0-DQ7), and CASH# transitioning LOW selects an access cycle for the upper byte (DQ8-DQ15). General byte and word access timing is shown in Figures 1 and 2.

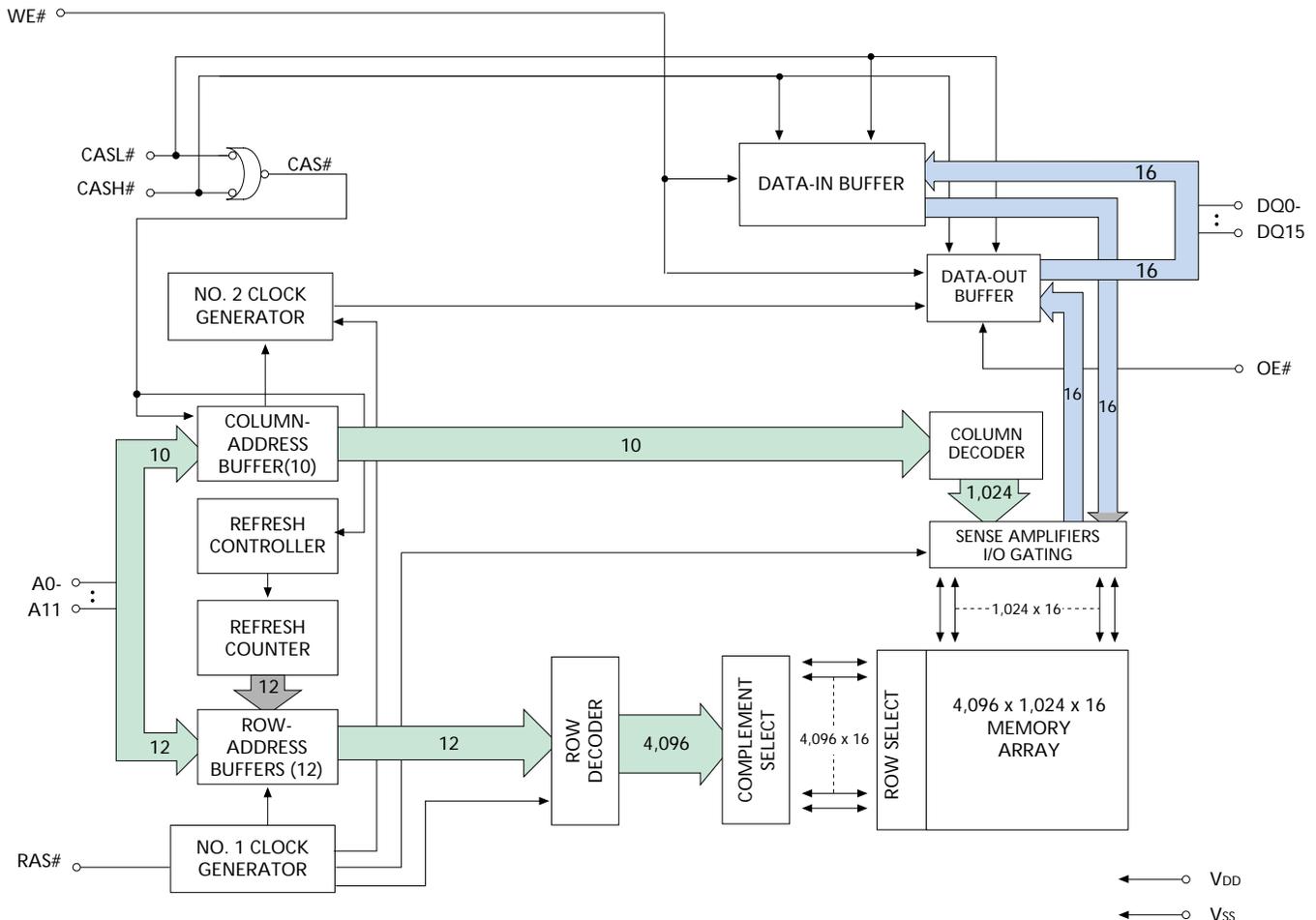
Additionally, both bytes must always be of the same mode of operation if both bytes are active. A CAS# precharge must be satisfied prior to changing modes of operation between the upper and lower bytes. For example, an EARLY WRITE on one byte and a LATE WRITE on the other byte are not allowed during the same cycle. However, an EARLY WRITE on one byte and

a LATE WRITE on the other byte, after a CAS# precharge has been satisfied, are permissible.

The WE# signal must be activated to execute a WRITE operation; otherwise a READ operation will be performed. The OE# signal must be activated to enable the DQ output drivers for a read access and can be deactivated to disable output data if necessary.

FAST-PAGE-MODE operations are always initiated with a row address strobed in by the RAS# signal, followed by a column address strobed in by CAS#, just like for single location accesses. However, subsequent column locations within the row may then be accessed at the page mode cycle time. This is accomplished by cycling CAS# while holding RAS# LOW and entering new column addresses with each CAS# cycle. Returning RAS# HIGH terminates the FAST-PAGE-MODE operation.

FUNCTIONAL BLOCK DIAGRAM MT4LC4M16F5 (12 row addresses)



DRAM REFRESH

The supply voltage must be maintained at the specified levels, and the refresh requirements must be met in order to retain stored data in the DRAM. The refresh requirements are met by refreshing all rows in the DRAM array at least once every 64ms. The recommended procedure is to execute 4,096 CBR REFRESH cycles, either uniformly spaced or grouped in bursts, every 64ms. The MT4LC4M16F5 internally refreshes one row for every CBR cycle, so executing 4,096 CBR cycles covers all rows. The CBR REFRESH will invoke the internal refresh counter for automatic RAS# address-

ing. Alternatively, RAS#-ONLY REFRESH capability is inherently provided. However, with this method some compatibility issues may become apparent. JEDEC strongly recommends the use of CBR REFRESH for this device.

STANDBY

Returning RAS# and CAS# HIGH terminates a memory cycle and decreases chip current to a reduced standby level. The chip is preconditioned for the next cycle during the RAS# HIGH time.

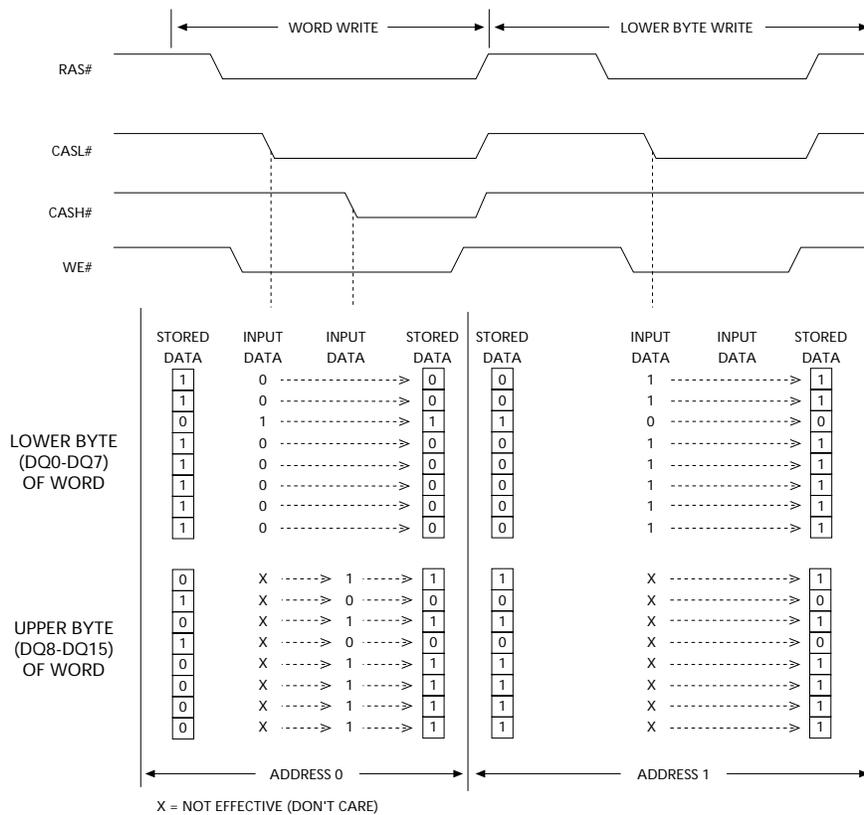


Figure 1
WORD and BYTE WRITE Example

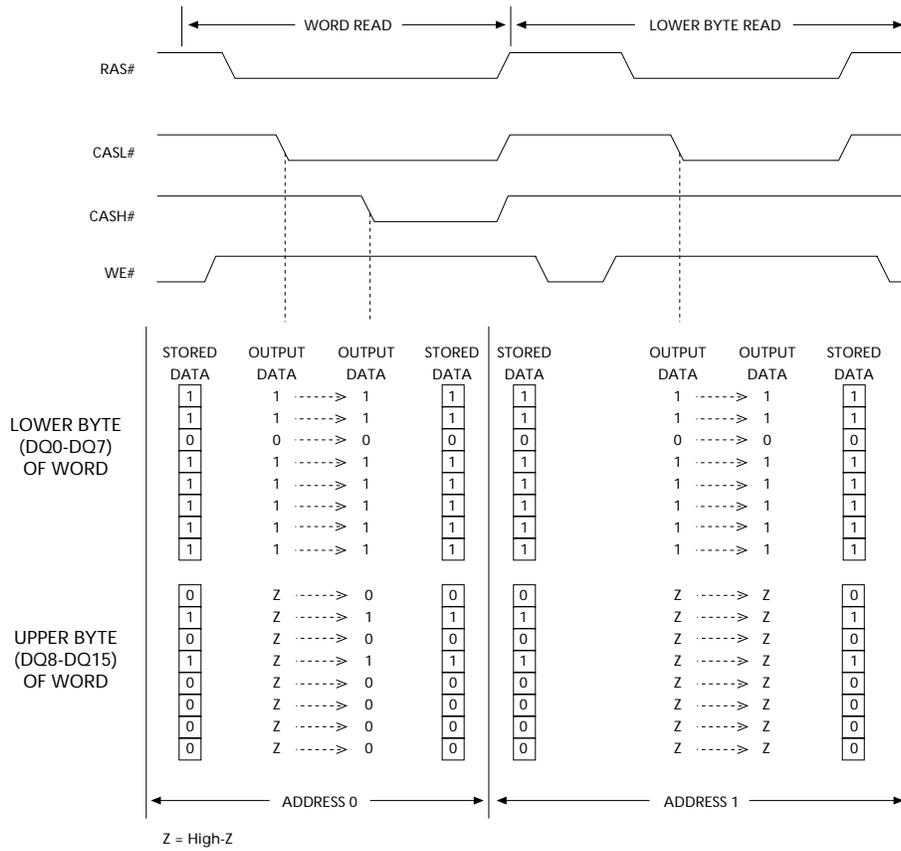


Figure 2
WORD and BYTE READ Example

ABSOLUTE MAXIMUM RATINGS*

| | |
|--|-----------------|
| Voltage on Vcc Relative to Vss | -1V to +4.6V |
| Voltage on NC, Inputs or I/O Pins Relative to Vss | -1V to +4.6V |
| Operating Temperature, T _A (ambient) ... | 0°C to +70°C |
| Storage Temperature (plastic) | -55°C to +150°C |
| Power Dissipation | 1W |

*Stresses greater than those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC ELECTRICAL CHARACTERISTICS AND OPERATING CONDITIONS

(Notes: 1, 5, 6) (V_{CC} = +3.3V ±0.3V)

| PARAMETER/CONDITION | SYMBOL | MIN | MAX | UNITS | NOTES |
|---|-----------------|------|-----------------------|-------|-------|
| SUPPLY VOLTAGE | V _{CC} | 3 | 3.6 | V | |
| INPUT HIGH VOLTAGE: Valid Logic 1; All inputs, I/Os and any NC | V _{IH} | 2 | V _{CC} + 0.3 | V | 37 |
| INPUT LOW VOLTAGE: Valid Logic 0; All inputs, I/Os and any NC | V _{IL} | -0.3 | 0.8 | V | 37 |
| INPUT LEAKAGE CURRENT: Any input at V _{IN} (0V ≤ V _{IN} ≤ V _{CC} + 0.3V); All other pins not under test = 0V | I _I | -2 | 2 | μA | |
| OUTPUT HIGH VOLTAGE: I _{OUT} = -2mA | V _{OH} | 2.4 | - | V | |
| OUTPUT LOW VOLTAGE: I _{OUT} = 2mA | V _{OL} | - | 0.4 | V | |
| OUTPUT LEAKAGE CURRENT: Any output at V _{OUT} (0V ≤ V _{OUT} ≤ V _{CC} + 0.3V); DQ is disabled and in High-Z state | I _{OZ} | -5 | 5 | μA | |

I_{DD} OPERATING CONDITIONS AND MAXIMUM LIMITS

(Notes: 1, 2, 3, 5, 6) (V_{CC} = +3.3V ±0.3V)

| PARAMETER/CONDITION | SYMBOL | SPEED | MAX | UNITS | NOTES |
|--|------------------|----------|------------|-------|-------|
| STANDBY CURRENT: TTL (RAS# = CAS# = V _{IH}) | I _{DD1} | ALL | 1 | mA | |
| STANDBY CURRENT: CMOS (RAS# = CAS# ≥ V _{CC} - 0.2V; DQs may be left open; Other inputs: V _{IN} ≥ V _{CC} - 0.2V or V _{IN} ≤ 0.2V) | I _{DD2} | ALL | 500 | μA | |
| OPERATING CURRENT: Random READ/WRITE Average power supply current (RAS#, CAS#, address cycling: t _{RC} = t _{RC} [MIN]) | I _{DD3} | -5 -6 | 150 165 | mA | 25 |
| OPERATING CURRENT: FAST PAGE MODE Average power supply current (RAS# = V _{IL} , CAS#, address cycling: t _{PC} = t _{PC} [MIN]) | I _{DD4} | -5 -6 | 105 95 | mA | 25 |
| REFRESH CURRENT: RAS# ONLY Average power supply current (RAS# cycling, CAS# = V _{IH} : t _{RC} = t _{RC} [MIN]) | I _{DD5} | -5 -6 | 150 165 | mA | 22 |
| REFRESH CURRENT: CBR Average power supply current (RAS#, CAS#, address cycling: t _{RC} = t _{RC} [MIN]) | I _{DD6} | -5 -6 | 150 165 | mA | 4, 7 |

CAPACITANCE

(Note: 2)

| PARAMETER | SYMBOL | MAX | UNITS |
|---|-----------------|-----|-------|
| Input Capacitance: Address pins | C _{I1} | 5 | pF |
| Input Capacitance: RAS#, CAS#, WE#, OE# | C _{I2} | 7 | pF |
| Input/Output Capacitance: DQ | C _{IO} | 7 | pF |

AC ELECTRICAL CHARACTERISTICS

(Notes: 5, 6, 7, 8, 9, 10, 11, 12, 13) (V_{CC} = +3.3V ±0.3V)

| AC CHARACTERISTICS PARAMETER | SYMBOL | -5 | | -6 | | UNITS | NOTES |
|---|-------------------|-----|--------|-----|--------|-------|------------|
| | | MIN | MAX | MIN | MAX | | |
| Access time from column address | t ^{AA} | | 25 | | 30 | ns | |
| Column-address hold time (referenced to RAS#) | t ^{AR} | 40 | | 45 | | ns | |
| Column-address setup time | t ^{ASC} | 0 | | 0 | | ns | 26 |
| Row-address setup time | t ^{ASR} | 0 | | 0 | | ns | |
| Column address to WE# delay time | t ^{AWD} | 48 | | 55 | | ns | 18 |
| Access time from CAS# | t ^{CAC} | | 13 | | 15 | ns | 28 |
| Column-address hold time | t ^{CAH} | 8 | | 10 | | ns | 26 |
| CAS# pulse width | t ^{CAS} | 13 | 10,000 | 15 | 10,000 | ns | 32, 34 |
| CAS# hold time (CBR Refresh) | t ^{CHR} | 15 | | 15 | | ns | 4, 27 |
| Last CAS# going LOW to first CAS# to return HIGH | t ^{CLCH} | 5 | | 5 | | ns | 29 |
| CAS# to output in Low-Z | t ^{CLZ} | 3 | | 3 | | ns | 26, 28 |
| CAS# precharge time (FAST PAGE MODE) | t ^{CP} | 8 | | 10 | | ns | 13, 32 |
| Access time from CAS# precharge | t ^{CPA} | | 30 | | 35 | ns | 27 |
| CAS# to RAS# precharge time | t ^{CRP} | 5 | | 5 | | ns | 27 |
| CAS# hold time | t ^{CSH} | 50 | | 60 | | ns | 27 |
| CAS# setup time (CBR Refresh) | t ^{CSR} | 5 | | 5 | | ns | 4, 26 |
| CAS# to WE# delay time | t ^{CWD} | 36 | | 40 | | ns | 18, 26 |
| WRITE command to CAS# lead time | t ^{CWL} | 13 | | 15 | | ns | 28 |
| Data-in hold time | t ^{DH} | 8 | | 10 | | ns | 19, 28 |
| Data-in setup time | t ^{DS} | 0 | | 0 | | ns | 19, 28 |
| Output disable | t ^{OD} | 3 | 13 | 3 | 15 | ns | 23, 24, 36 |
| Output enable time | t ^{OE} | | 13 | | 15 | ns | 20 |
| OE# hold time from WE# during READ-MODIFY-WRITE cycle | t ^{OEH} | 13 | | 15 | | ns | 24 |
| Output buffer turn-off delay | t ^{OFF} | 3 | 13 | 3 | 15 | ns | 17, 23, 28 |
| OE# setup prior to RAS# during HIDDEN REFRESH cycle | t ^{ORD} | 0 | | 0 | | ns | |
| FAST-PAGE-MODE READ or WRITE cycle time | t ^{PC} | 30 | | 35 | | ns | 30 |
| FAST-PAGE-MODE READ-WRITE cycle time | t ^{PRWC} | 76 | | 85 | | ns | 30 |
| Access time from RAS# | t ^{RAC} | | 50 | | 60 | ns | |
| RAS# to column-address delay time | t ^{RAD} | 13 | | 15 | | ns | 15 |
| Row-address hold time | t ^{RAH} | 8 | | 10 | | ns | |

AC ELECTRICAL CHARACTERISTICS

 (Notes: 5, 6, 7, 8, 9, 10, 11, 12, 13) ($V_{CC} = +3.3V \pm 0.3V$)

| AC CHARACTERISTICS | | -5 | | -6 | | | |
|--|------------|-----|---------|-----|---------|-------|--------|
| PARAMETER | SYMBOL | MIN | MAX | MIN | MAX | UNITS | NOTES |
| RAS# pulse width | t_{RAS} | 50 | 10,000 | 60 | 10,000 | ns | |
| RAS# pulse width (FAST PAGE MODE) | t_{RASP} | 50 | 125,000 | 60 | 125,000 | ns | |
| Random READ or WRITE cycle time | t_{RC} | 90 | | 110 | | ns | |
| RAS# to CAS# delay time | t_{RCD} | 18 | | 20 | | ns | 14, 26 |
| READ command hold time (referenced to CAS#) | t_{RCH} | 0 | | 0 | | ns | 16, 27 |
| READ command setup time | t_{RCS} | 0 | | 0 | | ns | 26 |
| Refresh period | t_{REF} | | 64 | | 64 | ms | 22 |
| RAS# precharge time | t_{RP} | 30 | | 40 | | ns | |
| RAS# to CAS# precharge time | t_{RPC} | 0 | | 0 | | ns | |
| READ command hold time (referenced to RAS#) | t_{RRH} | 0 | | 0 | | ns | 16 |
| RAS# hold time | t_{RSH} | 13 | | 15 | | ns | 35 |
| READ-WRITE cycle time | t_{RWC} | 131 | | 155 | | ns | |
| RAS# to WE# delay time | t_{RWD} | 73 | | 85 | | ns | 18 |
| WRITE command to RAS# lead time | t_{RWL} | 13 | | 15 | | ns | |
| Transition time (rise or fall) | t_T | 2 | 50 | 2 | 50 | ns | |
| WRITE command hold time | t_{WCH} | 8 | | 10 | | ns | 35 |
| WRITE command hold time (referenced to RAS#) | t_{WCR} | 40 | | 45 | | ns | |
| WE# command setup time | t_{WCS} | 0 | | 0 | | ns | 18, 26 |
| WRITE command pulse width | t_{WP} | 8 | | 10 | | ns | |
| WE# hold time (CBR Refresh) | t_{WRH} | 10 | | 10 | | ns | |
| WE# setup time (CBR Refresh) | t_{WRP} | 10 | | 10 | | ns | |

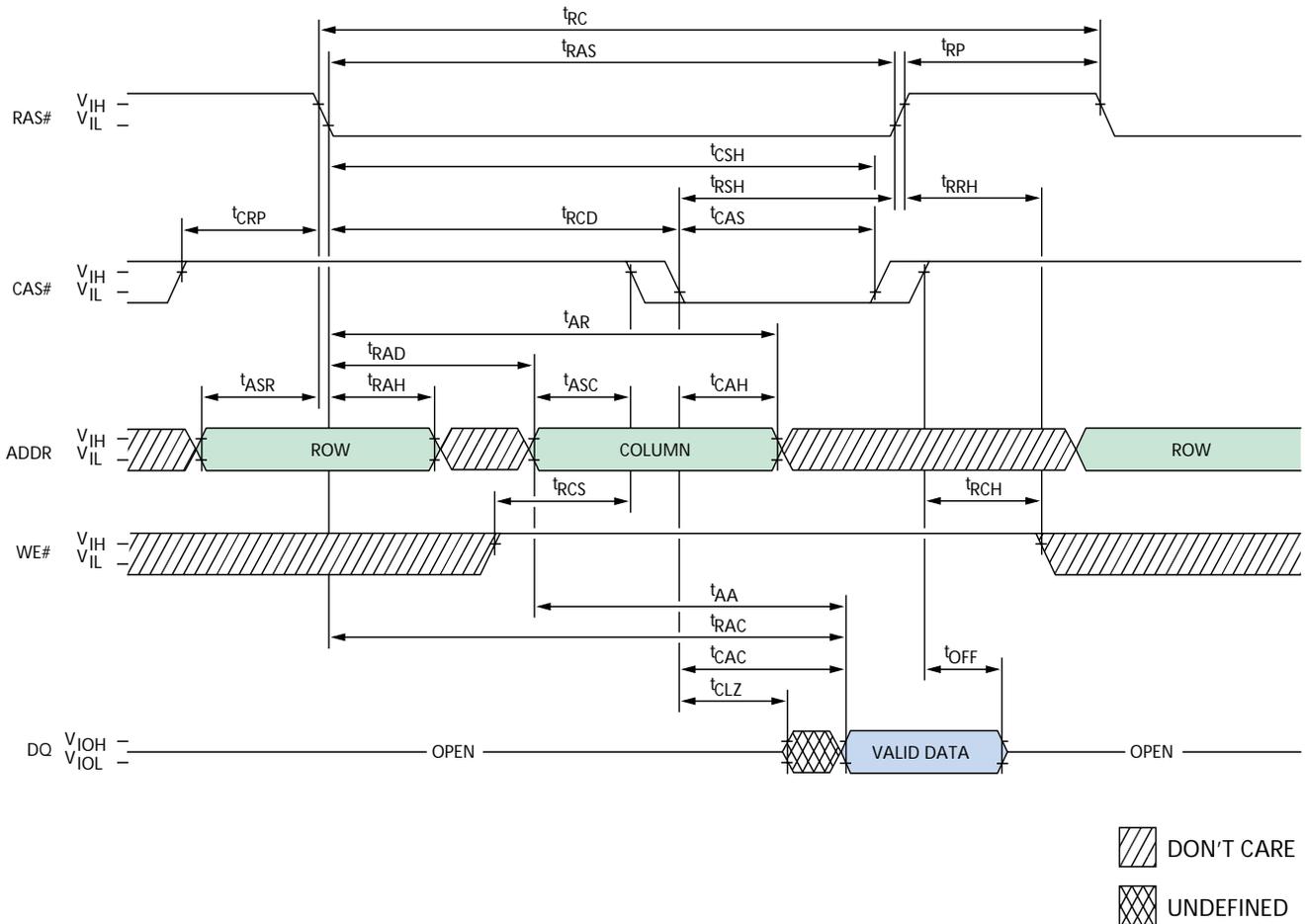
NOTES

1. All voltages referenced to V_{SS} .
2. This parameter is sampled. $V_{CC} = +3.3V$; $f = 1$ MHz.
3. I_{DD} is dependent on output loading and cycle rates. Specified values are obtained with minimum cycle time and the outputs open.
4. Enables on-chip refresh and address counters.
5. The minimum specifications are used only to indicate cycle time at which proper operation over the full temperature range is ensured.
6. An initial pause of 100 μ s is required after power-up, followed by eight RAS# refresh cycles (RAS#-ONLY or CBR with WE# HIGH), before proper device operation is ensured. The eight RAS# cycle wake-ups should be repeated any time the t_{REF} refresh requirement is exceeded.
7. AC characteristics assume $t_T = 5$ ns.
8. V_{IH} (MIN) and V_{IL} (MAX) are reference levels for measuring timing of input signals. Transition times are measured between V_{IH} and V_{IL} (or between V_{IL} and V_{IH}).
9. In addition to meeting the transition rate specification, all input signals must transit between V_{IH} and V_{IL} (or between V_{IL} and V_{IH}) in a monotonic manner.
10. If CAS# = V_{IH} , data output is High-Z.
11. If CAS# = V_{IL} , data output may contain data from the last valid READ cycle.
12. Measured with a load equivalent to two TTL gates, 100pF and $V_{OL} = 0.8V$ and $V_{OH} = 2V$.
13. If CAS# is LOW at the falling edge of RAS#, output data will be maintained from the previous cycle. To initiate a new cycle and clear the data-out buffer, CAS# must be pulsed HIGH for t_{CP} .
14. The t_{RCD} (MAX) limit is no longer specified. t_{RCD} (MAX) was specified as a reference point only. If t_{RCD} was greater than the specified t_{RCD} (MAX) limit, then access time was controlled exclusively by t_{CAC} (t_{RAC} [MIN] no longer applied). With or without the t_{RCD} limit, t_{AA} and t_{CAC} must always be met.
15. The t_{RAD} (MAX) limit is no longer specified. t_{RAD} (MAX) was specified as a reference point only. If t_{RAD} was greater than the specified t_{RAD} (MAX) limit, then access time was controlled exclusively by t_{AA} (t_{RAC} and t_{CAC} no longer applied). With or without the t_{RAD} (MAX) limit, t_{AA} , t_{RAC} , and t_{CAC} must always be met.
16. Either t_{RCH} or t_{RRH} must be satisfied for a READ cycle.
17. t_{OFF} (MAX) defines the time at which the output achieves the open circuit condition and is not referenced to V_{OH} or V_{OL} .
18. t_{WCS} , t_{RWD} , t_{AWD} , and t_{CWD} are not restrictive operating parameters. t_{WCS} applies to EARLY WRITE cycles. If $t_{WCS} > t_{WCS}$ (MIN), the cycle is an EARLY WRITE cycle and the data output will remain an open circuit throughout the entire cycle. t_{RWD} , t_{AWD} and t_{CWD} define READ-MODIFY-WRITE cycles. Meeting these limits allows for reading and disabling output data and then applying input data. The values shown were calculated for reference allowing 10ns for the external latching of read data and application of write data. OE# held HIGH and WE# taken LOW after CAS# goes LOW result in a LATE WRITE (OE#-controlled) cycle. t_{WCS} , t_{RWD} , t_{CWD} , and t_{AWD} are not applicable in a LATE WRITE cycle.
19. These parameters are referenced to CAS# leading edge in EARLY WRITE cycles and WE# leading edge in LATE WRITE or READ-MODIFY-WRITE cycles.
20. If OE# is tied permanently LOW, LATE WRITE, or READ-MODIFY-WRITE operations are not possible.
21. A HIDDEN REFRESH may also be performed after a WRITE cycle. In this case, WE# = LOW and OE# = HIGH.
22. RAS#-ONLY REFRESH requires that all 4,096 rows be refreshed at least once every 64ms. CBR REFRESH requires that at least 4,096 cycles be completed every 64ms.
23. The DQs go High-Z during READ cycles once t_{OD} or t_{OFF} occur. If CAS# goes HIGH before OE#, the DQs will go High-Z regardless of the state of OE#. If CAS# stays LOW while OE# is brought HIGH, the DQs will go High-Z. If OE# is brought back LOW (CAS# still LOW), the DQs will provide the previously read data.
24. LATE WRITE and READ-MODIFY-WRITE cycles must have both t_{OD} and t_{OE} met (OE# HIGH during WRITE cycle) in order to ensure that the output buffers will be open during the WRITE cycle. If OE# is taken back LOW while CAS# remains LOW, the DQs will remain open.
25. Column address changed once each cycle.
26. The first CASx# edge to transition LOW.
27. The last CASx# edge to transition HIGH.
28. Output parameter (DQx) is referenced to corresponding CAS# input; DQ0-DQ7 by CASL# and DQ8-DQ15 by CASH#.
29. Last falling CASx# edge to first rising CASx# edge.

NOTES (continued)

30. Last rising CASx# edge to next cycle's last rising CASx# edge.
31. Last rising CASx# edge to first falling CASx# edge.
32. First DQs controlled by the first CASx# to go LOW.
33. Last DQs controlled by the last CASx# to go HIGH.
34. Each CASx# must meet minimum pulse width.
35. Last CASx# to go LOW.
36. All DQs controlled, regardless CASL# and CASH#.
37. V_{IH} overshoot: $V_{IH} (MAX) = V_{CC} + 2V$ for a pulse width $\leq 3ns$, and the pulse width cannot be greater than one third of the cycle rate. V_{IL} undershoot: $V_{IL} (MIN) = -2V$ for a pulse width $\leq 3ns$, and the pulse width cannot be greater than one third of the cycle rate.

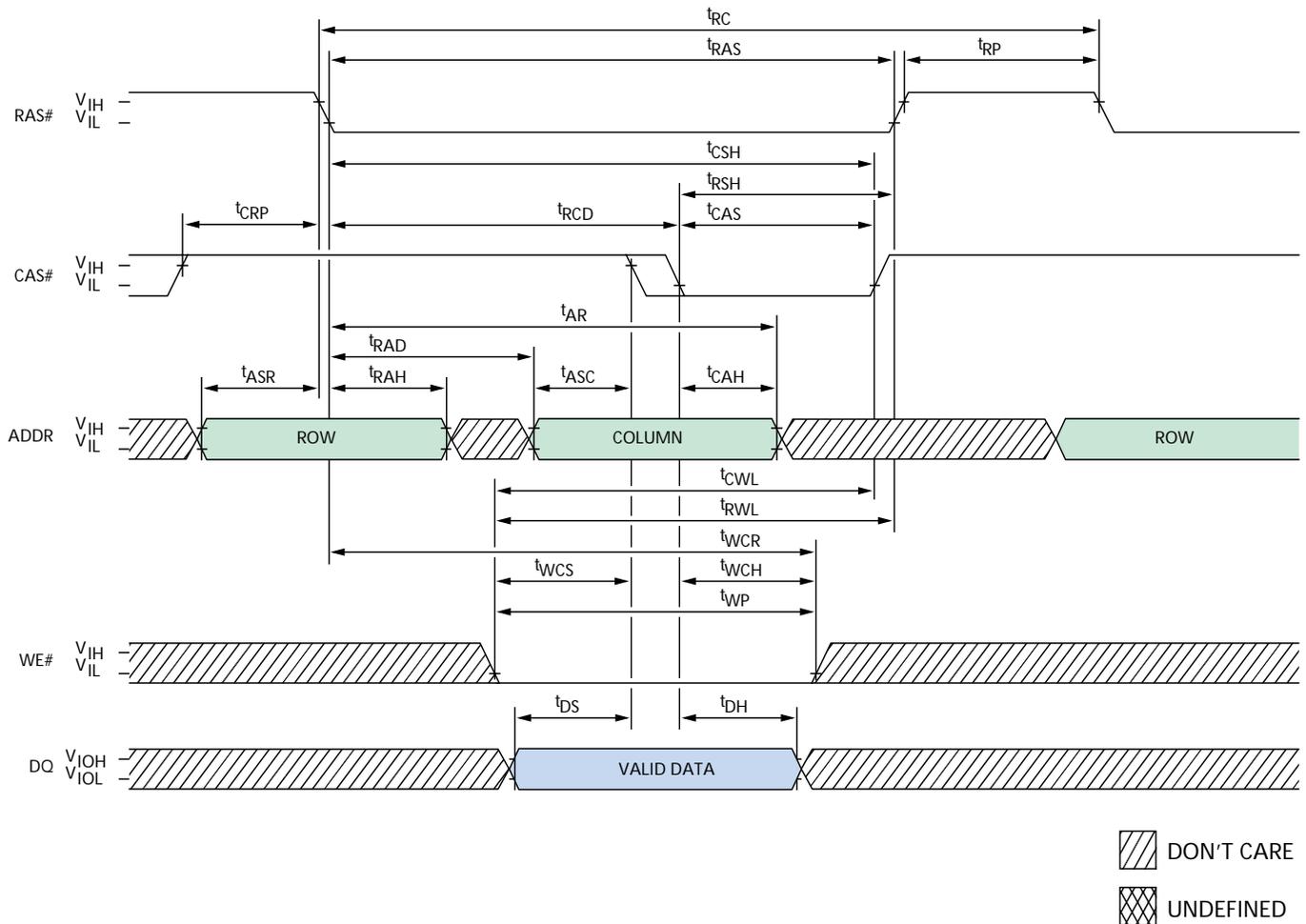
READ CYCLE



TIMING PARAMETERS

| SYMBOL | -5 | | -6 | | UNITS |
|-------------------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| t _{AA} | | 25 | | 30 | ns |
| t _{AR} | 40 | | 45 | | ns |
| t _{ASC} | 0 | | 0 | | ns |
| t _{ASR} | 0 | | 0 | | ns |
| t _{CAC} | | 13 | | 15 | ns |
| t _{CAH} | 8 | | 10 | | ns |
| t _{CAS} | 13 | 10,000 | 15 | 10,000 | ns |
| t _{CLCH} | 5 | | 5 | | ns |
| t _{CLZ} | 3 | | 3 | | ns |
| t _{CRP} | 5 | | 5 | | ns |
| t _{CSH} | 50 | | 60 | | ns |
| t _{OD} | 3 | 13 | 3 | 15 | ns |
| t _{OE} | | 13 | | 15 | ns |

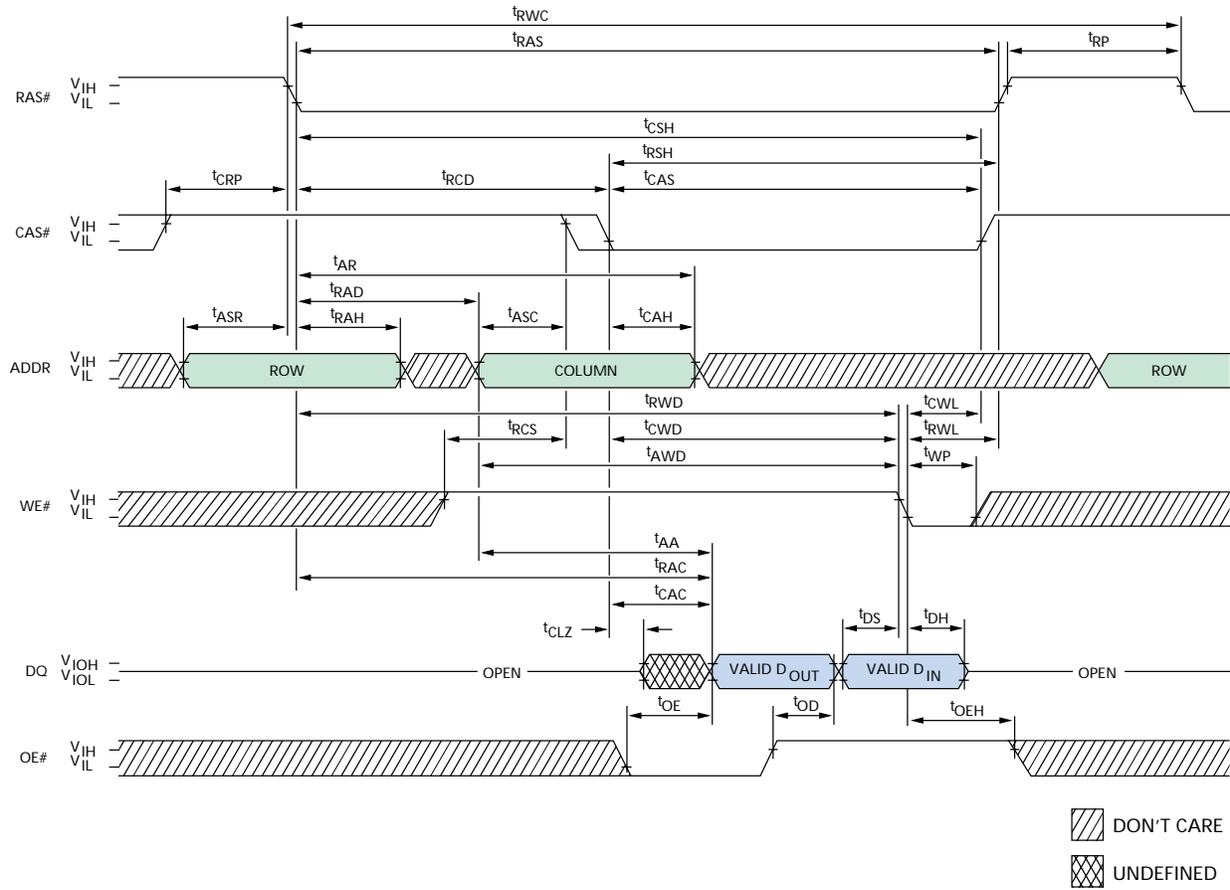
| SYMBOL | -5 | | -6 | | UNITS |
|------------------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| t _{OFF} | 3 | 13 | 3 | 15 | ns |
| t _{RAC} | | 50 | | 60 | ns |
| t _{RAD} | 13 | | 15 | | ns |
| t _{RAH} | 8 | | 10 | | ns |
| t _{RAS} | 50 | 10,000 | 60 | 10,000 | ns |
| t _{RC} | 90 | | 110 | | ns |
| t _{RCD} | 18 | | 20 | | ns |
| t _{RCH} | 0 | | 0 | | ns |
| t _{RCS} | 0 | | 0 | | ns |
| t _{RP} | 30 | | 40 | | ns |
| t _{RRH} | 0 | | 0 | | ns |
| t _{RSH} | 13 | | 15 | | ns |

EARLY WRITE CYCLE

TIMING PARAMETERS

| SYMBOL | -5 | | -6 | | UNITS |
|------------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| t_{AR} | 40 | | 45 | | ns |
| t_{ASC} | 0 | | 0 | | ns |
| t_{ASR} | 0 | | 0 | | ns |
| t_{CAH} | 8 | | 10 | | ns |
| t_{CAS} | 13 | 10,000 | 15 | 10,000 | ns |
| t_{CLCH} | 5 | | 5 | | ns |
| t_{CRP} | 5 | | 5 | | ns |
| t_{CSH} | 50 | | 60 | | ns |
| t_{CWL} | 13 | | 15 | | ns |
| t_{DH} | 8 | | 10 | | ns |
| t_{DS} | 0 | | 0 | | ns |
| t_{RAD} | 13 | | 15 | | ns |

| SYMBOL | -5 | | -6 | | UNITS |
|-----------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| t_{RAH} | 8 | | 10 | | ns |
| t_{RAS} | 50 | 10,000 | 60 | 10,000 | ns |
| t_{RC} | 90 | | 110 | | ns |
| t_{RCD} | 18 | | 20 | | ns |
| t_{RP} | 30 | | 40 | | ns |
| t_{RSH} | 13 | | 15 | | ns |
| t_{RWL} | 13 | | 15 | | ns |
| t_{WCH} | 8 | | 10 | | ns |
| t_{WCR} | 40 | | 45 | | ns |
| t_{WCS} | 0 | | 0 | | ns |
| t_{WP} | 8 | | 10 | | ns |

READ-WRITE CYCLE (LATE WRITE and READ-MODIFY-WRITE cycles)

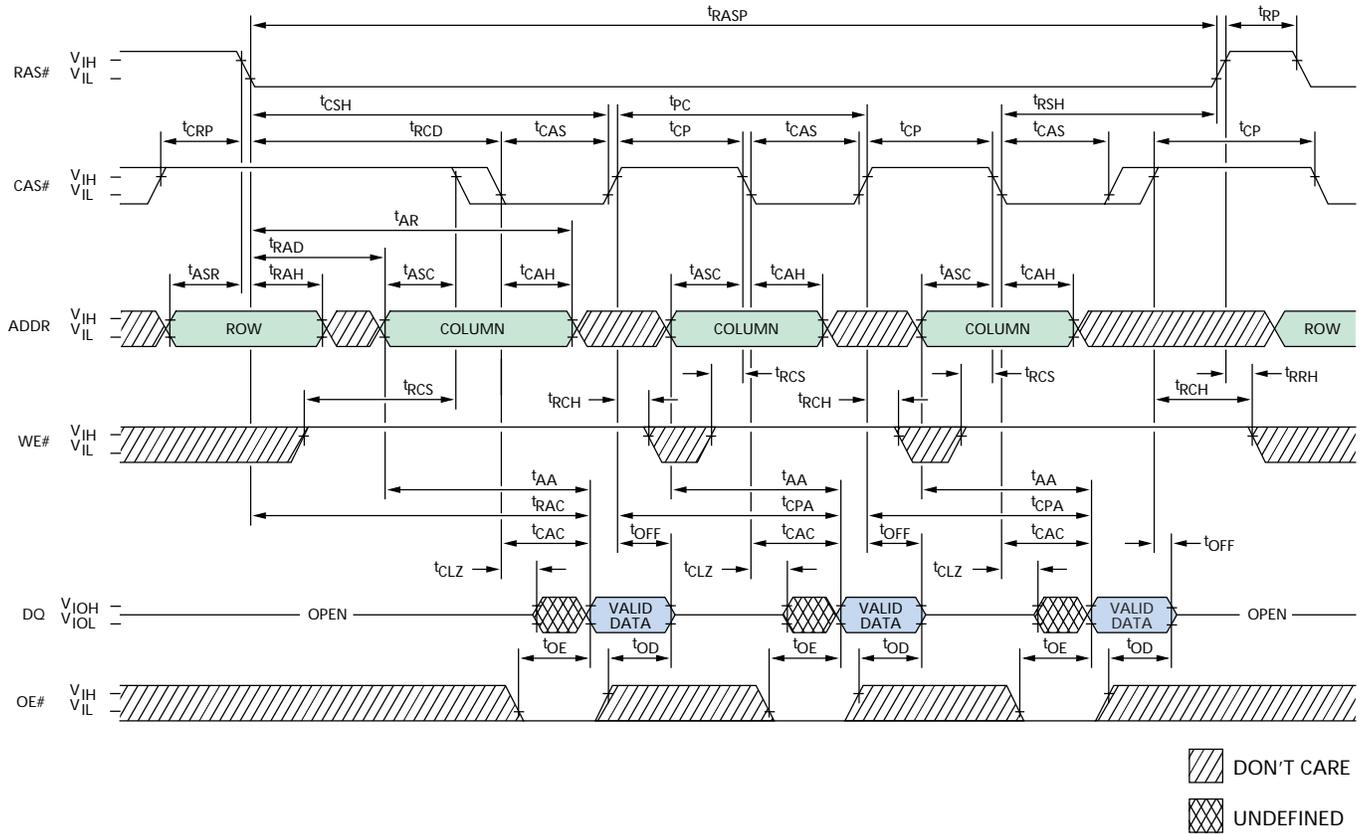


DON'T CARE
 UNDEFINED

TIMING PARAMETERS

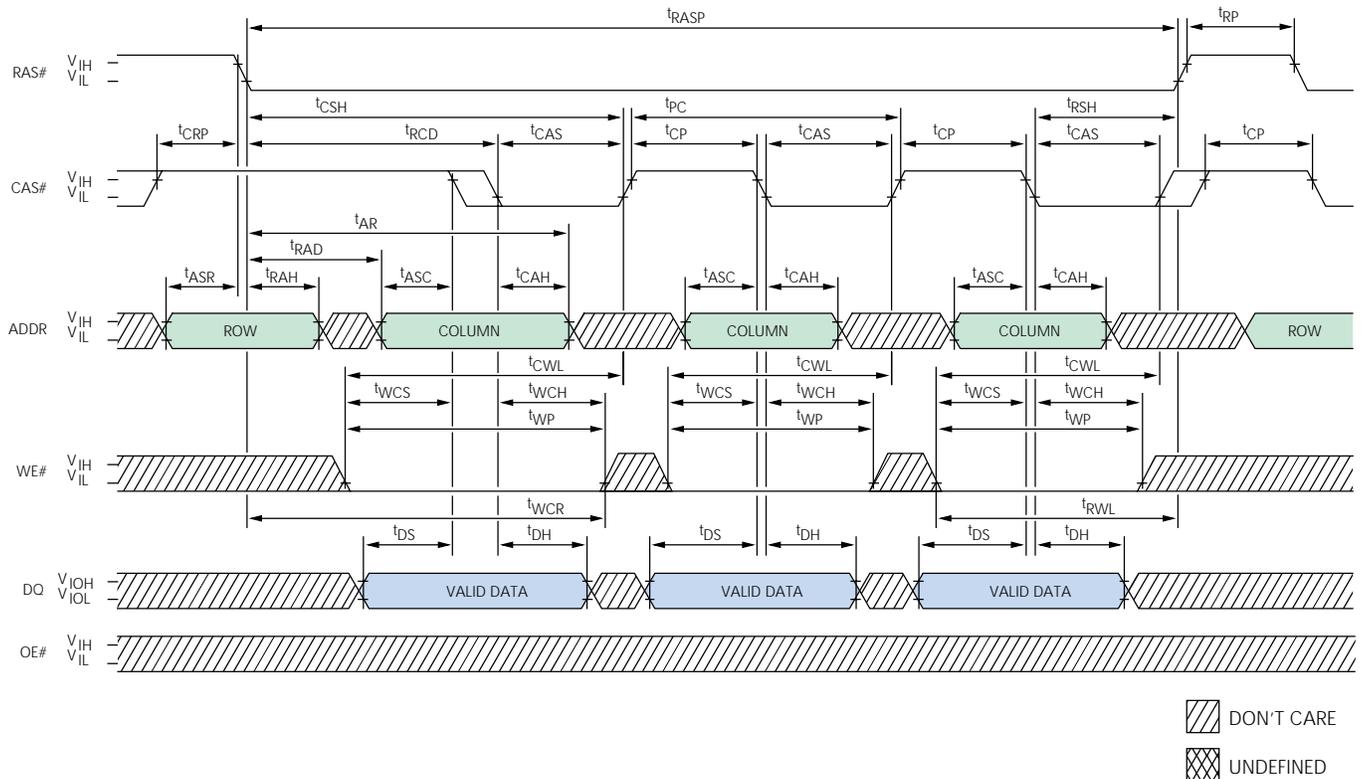
| SYMBOL | -5 | | -6 | | UNITS |
|------------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| t_{AA} | | 25 | | 30 | ns |
| t_{AR} | 40 | | 45 | | ns |
| t_{ASC} | 0 | | 0 | | ns |
| t_{ASR} | 0 | | 0 | | ns |
| t_{AWD} | 48 | | 55 | | ns |
| t_{CAC} | | 13 | | 15 | ns |
| t_{CAH} | 8 | | 10 | | ns |
| t_{CAS} | 13 | 10,000 | 15 | 10,000 | ns |
| t_{CLCH} | 5 | | 5 | | ns |
| t_{CLZ} | 3 | | 3 | | ns |
| t_{CRP} | 5 | | 5 | | ns |
| t_{CSH} | 50 | | 60 | | ns |
| t_{CWD} | 36 | | 40 | | ns |
| t_{CWL} | 13 | | 15 | | ns |
| t_{DH} | 8 | | 10 | | ns |
| t_{DS} | 0 | | 0 | | ns |

| SYMBOL | -5 | | -6 | | UNITS |
|-----------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| t_{OD} | 3 | 13 | 3 | 15 | ns |
| t_{OE} | | 13 | | 15 | ns |
| t_{OEH} | 13 | | 15 | | ns |
| t_{RAC} | | 50 | | 60 | ns |
| t_{RAD} | 13 | | 15 | | ns |
| t_{RAH} | 8 | | 10 | | ns |
| t_{RAS} | 50 | 10,000 | 60 | 10,000 | ns |
| t_{RCD} | 18 | | 20 | | ns |
| t_{RCS} | 0 | | 0 | | ns |
| t_{RP} | 30 | | 40 | | ns |
| t_{RSH} | 13 | | 15 | | ns |
| t_{RWC} | 131 | | 155 | | ns |
| t_{RWD} | 73 | | 85 | | ns |
| t_{RWL} | 13 | | 15 | | ns |
| t_{WP} | 8 | | 10 | | ns |

FAST-PAGE-MODE READ CYCLE

TIMING PARAMETERS

| SYMBOL | -5 | | -6 | | UNITS |
|-------------------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| t _{AA} | | 25 | | 30 | ns |
| t _{AR} | 40 | | 45 | | ns |
| t _{ASC} | 0 | | 0 | | ns |
| t _{ASR} | 0 | | 0 | | ns |
| t _{CAC} | | 13 | | 15 | ns |
| t _{CAH} | 8 | | 10 | | ns |
| t _{CAS} | 13 | 10,000 | 15 | 10,000 | ns |
| t _{CLCH} | 5 | | 5 | | ns |
| t _{CLZ} | 3 | | 3 | | ns |
| t _{CP} | 8 | | 10 | | ns |
| t _{CPA} | | 30 | | 35 | ns |
| t _{CRP} | 5 | | 5 | | ns |
| t _{CSH} | 50 | | 60 | | ns |
| t _{OD} | 3 | 13 | 3 | 15 | ns |

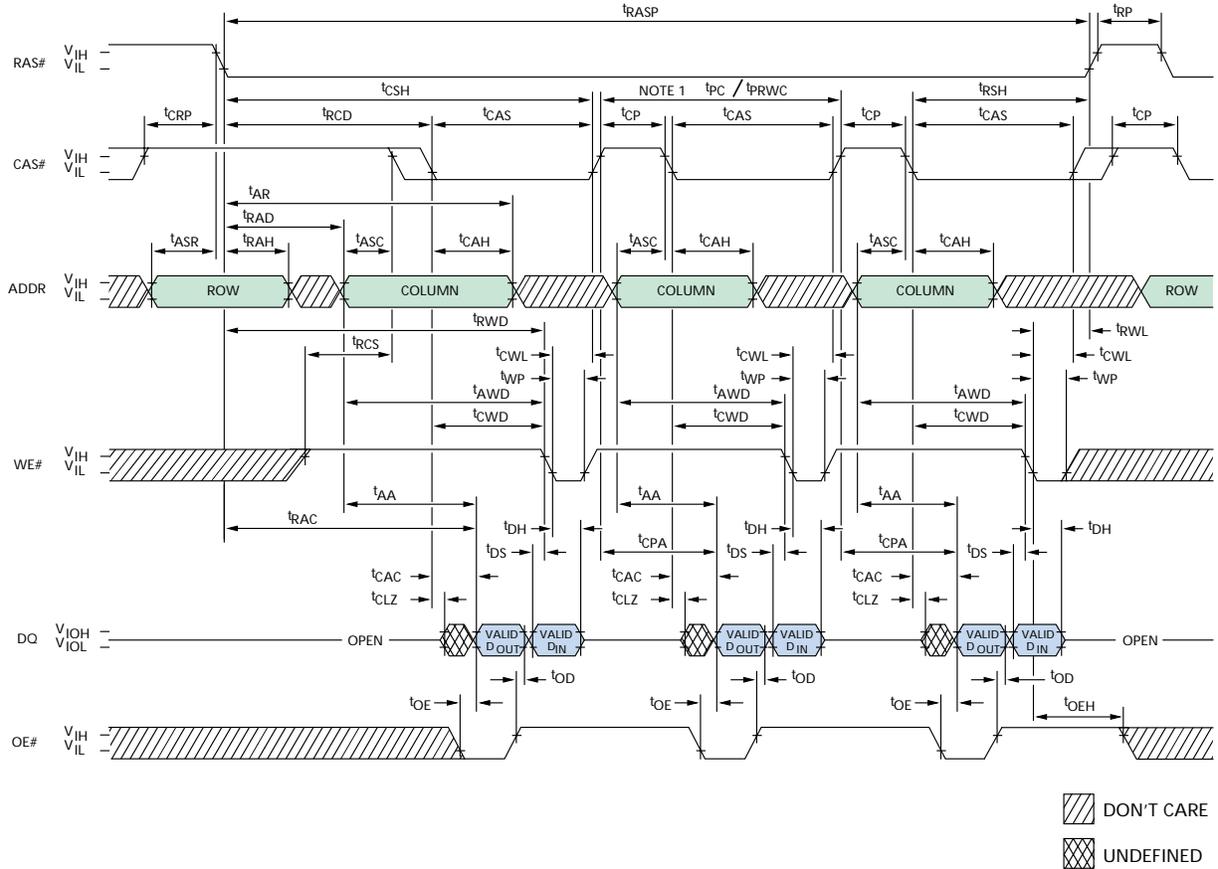
| SYMBOL | -5 | | -6 | | UNITS |
|-------------------|-----|---------|-----|---------|-------|
| | MIN | MAX | MIN | MAX | |
| t _{OE} | | 13 | | 15 | ns |
| t _{OFF} | 3 | 13 | 3 | 15 | ns |
| t _{PC} | 30 | | 35 | | ns |
| t _{RAC} | | 50 | | 60 | ns |
| t _{RAD} | 13 | | 15 | | ns |
| t _{RAH} | 8 | | 10 | | ns |
| t _{RASP} | 50 | 125,000 | 60 | 125,000 | ns |
| t _{RCD} | 18 | | 20 | | ns |
| t _{RCH} | 0 | | 0 | | ns |
| t _{RCS} | 0 | | 0 | | ns |
| t _{RP} | 30 | | 40 | | ns |
| t _{RRH} | 0 | | 0 | | ns |
| t _{RSH} | 13 | | 15 | | ns |

FAST-PAGE-MODE EARLY WRITE CYCLE

TIMING PARAMETERS

| SYMBOL | -5 | | -6 | | UNITS |
|-------------------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| t _{AR} | 40 | | 45 | | ns |
| t _{ASC} | 0 | | 0 | | ns |
| t _{ASR} | 0 | | 0 | | ns |
| t _{CAH} | 8 | | 10 | | ns |
| t _{CAS} | 13 | 10,000 | 15 | 10,000 | ns |
| t _{CLCH} | 5 | | 5 | | ns |
| t _{CP} | 8 | | 10 | | ns |
| t _{CRP} | 5 | | 5 | | ns |
| t _{CSH} | 50 | | 60 | | ns |
| t _{CWL} | 13 | | 15 | | ns |
| t _{DH} | 8 | | 10 | | ns |
| t _{DS} | 0 | | 0 | | ns |

| SYMBOL | -5 | | -6 | | UNITS |
|-------------------|-----|---------|-----|---------|-------|
| | MIN | MAX | MIN | MAX | |
| t _{PC} | 30 | | 35 | | ns |
| t _{RAD} | 13 | | 15 | | ns |
| t _{RAH} | 8 | | 10 | | ns |
| t _{RASP} | 50 | 125,000 | 60 | 125,000 | ns |
| t _{RCD} | 18 | | 20 | | ns |
| t _{RP} | 30 | | 40 | | ns |
| t _{RSH} | 13 | | 15 | | ns |
| t _{RWL} | 13 | | 15 | | ns |
| t _{WCH} | 8 | | 10 | | ns |
| t _{WCR} | 40 | | 45 | | ns |
| t _{WCS} | 0 | | 0 | | ns |
| t _{WP} | 8 | | 10 | | ns |

FAST-PAGE-MODE READ-WRITE CYCLE (LATE WRITE and READ-MODIFY-WRITE cycles)



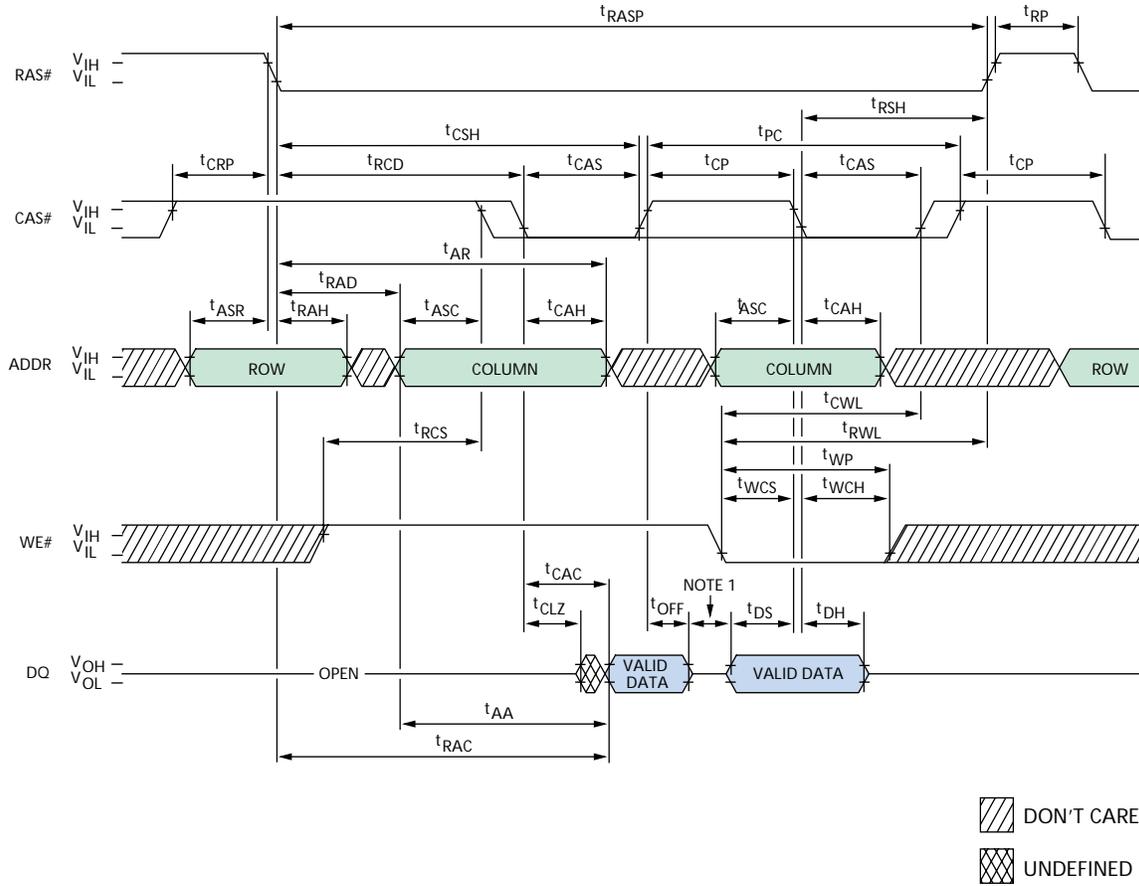
TIMING PARAMETERS

| SYMBOL | -5 | | -6 | | UNITS |
|--------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| tAA | | 25 | | 30 | ns |
| tAR | 40 | | 45 | | ns |
| tASC | 0 | | 0 | | ns |
| tASR | 0 | | 0 | | ns |
| tAWD | 48 | | 55 | | ns |
| tCAC | | 13 | | 15 | ns |
| tCAH | 8 | | 10 | | ns |
| tCAS | 13 | 10,000 | 15 | 10,000 | ns |
| tCLCH | 5 | | 5 | | ns |
| tCLZ | 3 | | 3 | | ns |
| tCP | 8 | | 10 | | ns |
| tCPA | | 30 | | 35 | ns |
| tCRP | 5 | | 5 | | ns |
| tCSH | 50 | | 60 | | ns |
| tCWD | 36 | | 40 | | ns |
| tCWL | 13 | | 15 | | ns |
| tDH | 8 | | 10 | | ns |

| SYMBOL | -5 | | -6 | | UNITS |
|--------|-----|---------|-----|---------|-------|
| | MIN | MAX | MIN | MAX | |
| tDS | 0 | | 0 | | ns |
| tOD | 3 | 13 | 3 | 15 | ns |
| tOE | | 13 | | 15 | ns |
| tOEH | 13 | | 15 | | ns |
| tPC | 30 | | 35 | | ns |
| tPRWC | 76 | | 85 | | ns |
| tRAC | | 50 | | 60 | ns |
| tRAD | 13 | | 15 | | ns |
| tRAH | 8 | | 10 | | ns |
| tRASP | 50 | 125,000 | 60 | 125,000 | ns |
| tRCD | 18 | | 20 | | ns |
| tRCS | 0 | | 0 | | ns |
| tRP | 30 | | 40 | | ns |
| tRSH | 13 | | 15 | | ns |
| tRWD | 73 | | 85 | | ns |
| tRWL | 13 | | 15 | | ns |
| tWP | 8 | | 10 | | ns |

NOTE: 1. tPC is for LATE WRITE only.

FAST-PAGE-MODE READ EARLY WRITE CYCLE (Pseudo READ-MODIFY-WRITE)



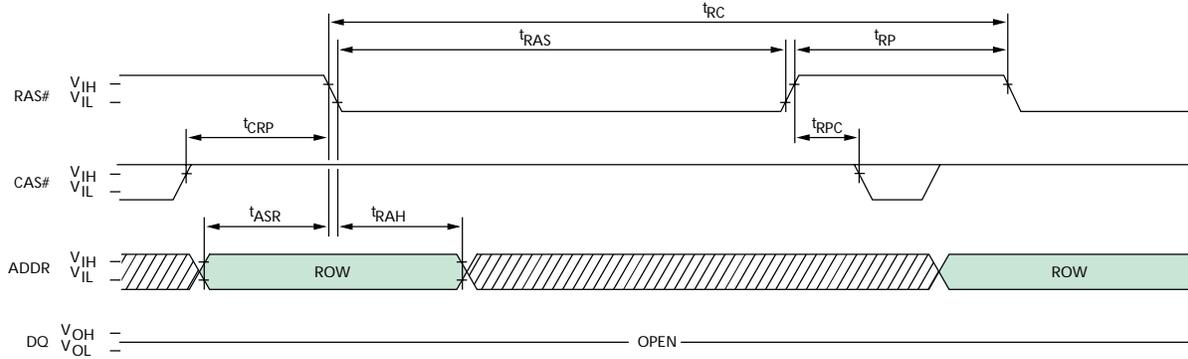
TIMING PARAMETERS

| SYMBOL | -5 | | -6 | | UNITS |
|--------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| tAA | | 25 | | 30 | ns |
| tAR | 40 | | 45 | | ns |
| tASC | 0 | | 0 | | ns |
| tASR | 0 | | 0 | | ns |
| tCAC | | 13 | | 15 | ns |
| tCAH | 8 | | 10 | | ns |
| tCAS | 13 | 10,000 | 15 | 10,000 | ns |
| tCLZ | 3 | | 3 | | ns |
| tCP | 8 | | 10 | | ns |
| tCRP | 5 | | 5 | | ns |
| tCSH | 50 | | 60 | | ns |
| tCWL | 13 | | 15 | | ns |
| tDH | 8 | | 10 | | ns |
| tDS | 0 | | 0 | | ns |

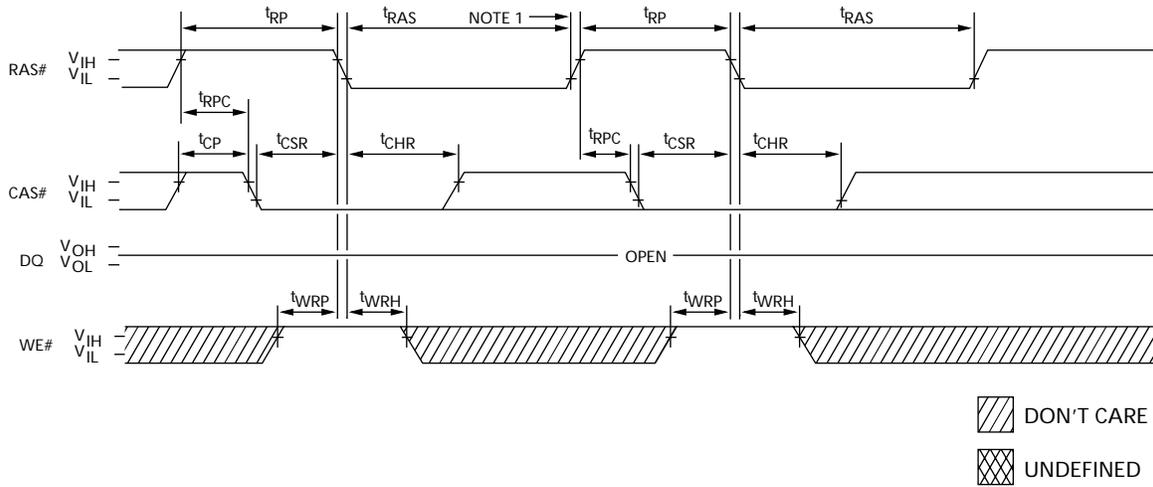
| SYMBOL | -5 | | -6 | | UNITS |
|--------|-----|---------|-----|---------|-------|
| | MIN | MAX | MIN | MAX | |
| tOFF | 3 | 13 | 3 | 15 | ns |
| tPC | 30 | | 35 | | ns |
| tRAC | | 50 | | 60 | ns |
| tRAD | 13 | | 15 | | ns |
| tRAH | 8 | | 10 | | ns |
| tRASP | 50 | 125,000 | 60 | 125,000 | ns |
| tRCD | 18 | | 20 | | ns |
| tRCS | 0 | | 0 | | ns |
| tRP | 30 | | 40 | | ns |
| tRSH | 13 | | 15 | | ns |
| tRWL | 13 | | 15 | | ns |
| tWCH | 8 | | 10 | | ns |
| tWCS | 0 | | 0 | | ns |
| tWP | 8 | | 10 | | ns |

NOTE: 1. Do not drive input data prior to output data going High-Z.

RAS#-ONLY REFRESH CYCLE (OE# and WE# = DON'T CARE)



CBR REFRESH CYCLE (Addresses and OE# = DON'T CARE)



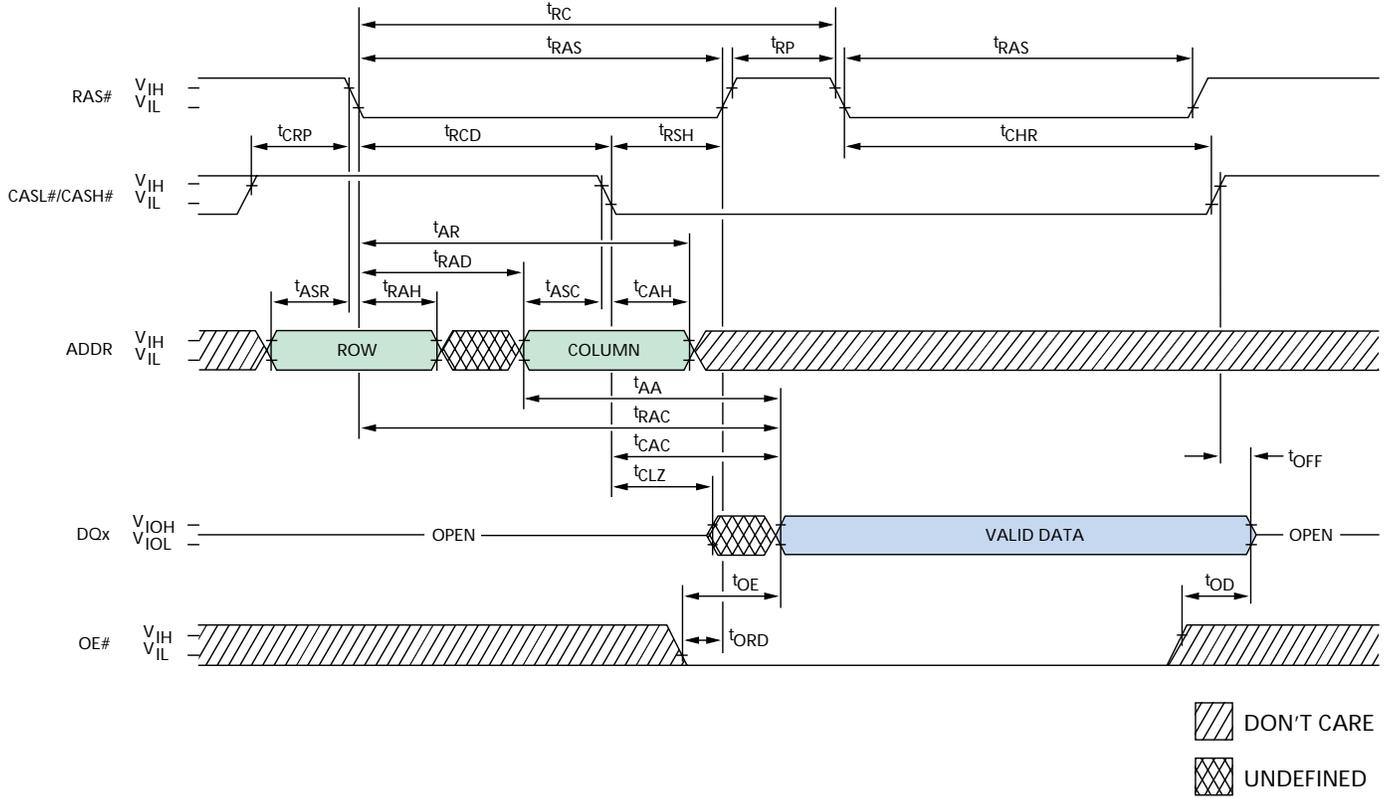
TIMING PARAMETERS

| SYMBOL | -5 | | -6 | | UNITS |
|-----------|-----|-----|-----|-----|-------|
| | MIN | MAX | MIN | MAX | |
| t_{ASR} | 0 | | 0 | | ns |
| t_{CHR} | 15 | | 15 | | ns |
| t_{CP} | 8 | | 10 | | ns |
| t_{CRP} | 5 | | 5 | | ns |
| t_{CSR} | 5 | | 5 | | ns |
| t_{RAH} | 8 | | 10 | | ns |

| SYMBOL | -5 | | -6 | | UNITS |
|-----------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| t_{RAS} | 50 | 10,000 | 60 | 10,000 | ns |
| t_{RC} | 90 | | 110 | | ns |
| t_{RP} | 30 | | 40 | | ns |
| t_{RPC} | 0 | | 0 | | ns |
| t_{WRH} | 10 | | 10 | | ns |
| t_{WRP} | 10 | | 10 | | ns |

NOTE: 1. End of first CBR REFRESH cycle.

HIDDEN REFRESH CYCLE ¹ (WE# = HIGH; OE# = LOW)



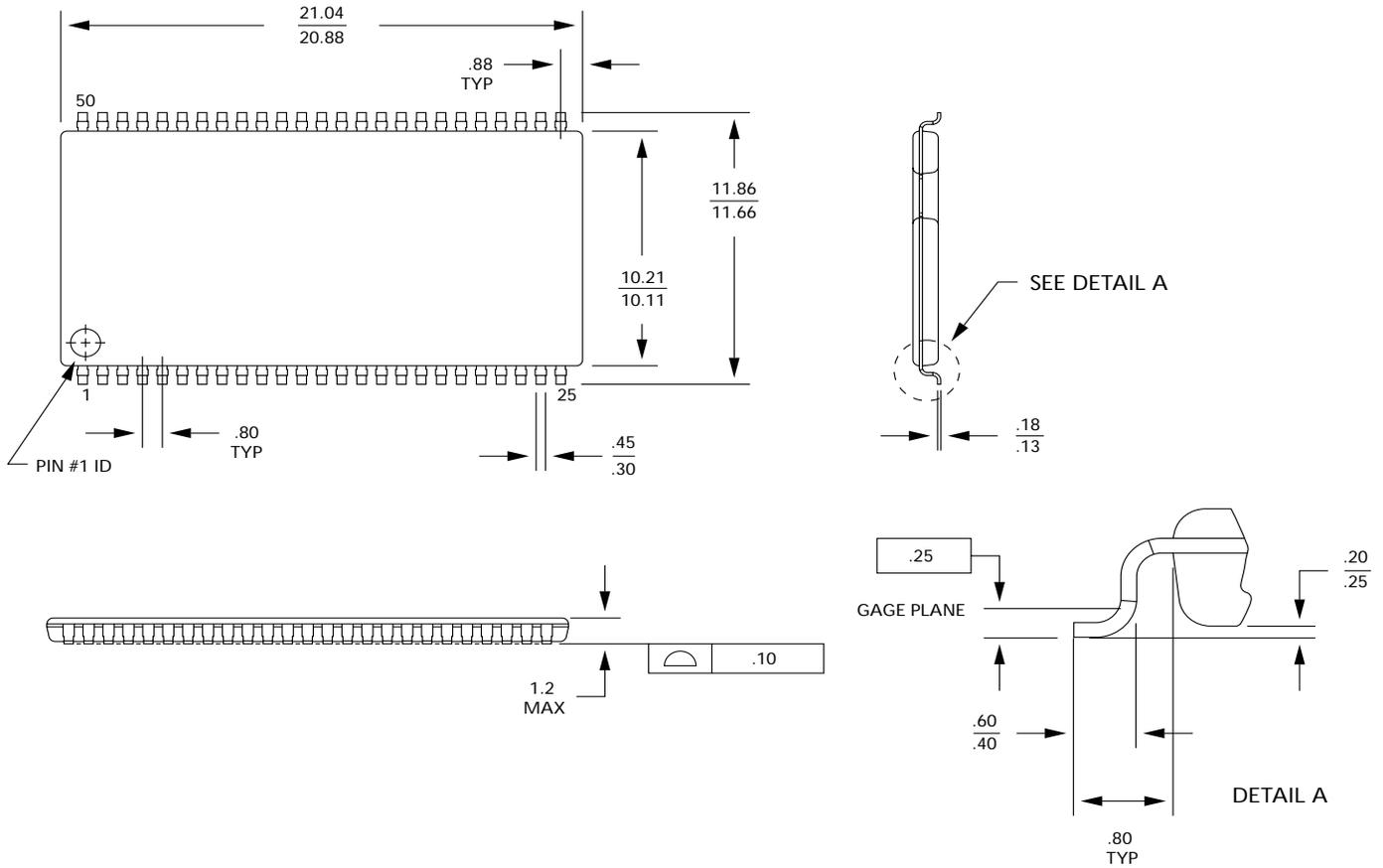
TIMING PARAMETERS

| SYMBOL | -5 | | -6 | | UNITS |
|--------|-----|-----|-----|-----|-------|
| | MIN | MAX | MIN | MAX | |
| tAA | | 25 | | 30 | ns |
| tAR | 40 | | 45 | | ns |
| tASC | 0 | | 0 | | ns |
| tASR | 0 | | 0 | | ns |
| tCAC | | 13 | | 15 | ns |
| tCAH | 8 | | 10 | | ns |
| tCHR | 15 | | 15 | | ns |
| tCLZ | 3 | | 3 | | ns |
| tCRP | 5 | | 5 | | ns |
| tOD | 3 | 13 | 3 | 15 | ns |

| SYMBOL | -5 | | -6 | | UNITS |
|--------|-----|--------|-----|--------|-------|
| | MIN | MAX | MIN | MAX | |
| tOE | | 13 | | 15 | ns |
| tOFF | 3 | 13 | 3 | 15 | ns |
| tORD | 0 | | 0 | | ns |
| tRAC | | 50 | | 60 | ns |
| tRAD | 13 | | 15 | | ns |
| tRAH | 8 | | 10 | | ns |
| tRAS | 50 | 10,000 | 60 | 10,000 | ns |
| tRCD | 18 | | 20 | | ns |
| tRP | 30 | | 40 | | ns |
| tRSH | 13 | | 15 | | ns |

NOTE: 1. A HIDDEN REFRESH may also be performed after a WRITE cycle. In this case, WE# is LOW and OE# is HIGH.

50-PIN PLASTIC TSOP (400 mil)



- NOTE:** 1. All dimensions in millimeters MAX or typical where noted.
MIN
2. Package width and length do not include mold protrusion; allowable mold protrusion is .25mm per side.



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